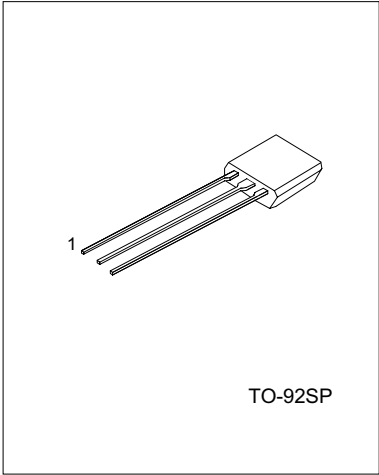


CAPACITOR MICROPHONE
APPLICATIONS

FEATURES

- *Especially Suited for use in Audio, Telephone Capacitor Microphones
- *Excellent Voltage characteristic
- *Excellent Transient Characteristic



1:SOURCE 2:GATE 3. DRAIN

ABSOLUTE MAXIMUM RATINGS (Ta=25°C ,unless otherwise specified)

PARAMETER	SYMBOL	RATING	UNIT
Gate Drain Voltage	V _{GDO}	-20	V
Gate Current	I _G	10	mA
Drain Current	I _D	1	mA
Power Dissipation	P _D	100	mW
Junctin Temperature	T _J	125	°C
Storage Temperature	T _{STG}	-55~+125	°C

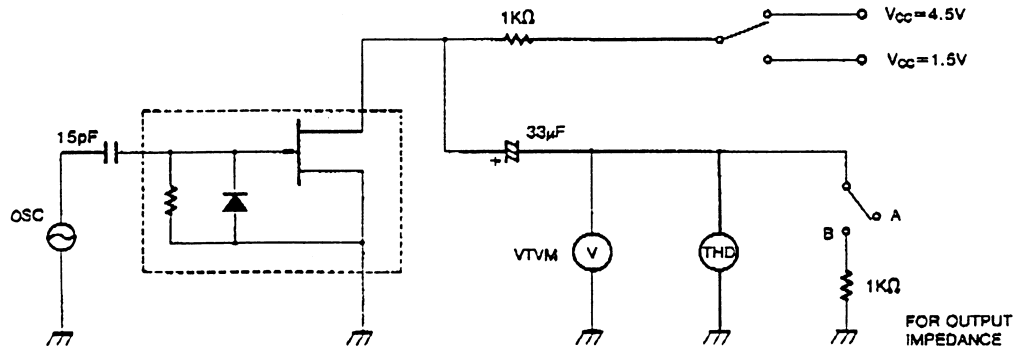
ELECTRICAL CHARACTERISTICS(Ta=25°C,unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Gate Drain Breakdown Voltage	BV _{GDO}	I _G =-100μA	-20			V
Gate Source Cut off Voltage	V _{GS(off)}	V _{DS} =5V,I _D =1μA		-0.6	-1.5	V
Drain Current	I _{DSS}	V _{DS} =5V,V _{GS} =0	100		800	μA
Forward Transfer Admittance	IY _{FSL}	V _{DS} =5V,V _{GS} =0,f=1KHz	0.4	1.2		mS
Input Capacitance	C _{ISS}	V _{DS} =5V,V _{GS} =0,f=1MHz		3.5		pF
Output Capacitance	C _{RSS}	V _{DS} =5V,V _{GS} =0,f=1MHz		0.65		pF

CLASSIFICATION OF I_{DSS}

RANK	A	B	C	D	E
I _{DSS} (μA)	100-170	150-240	210-350	320-480	440-800

TEST CIRCUIT(Ta=25°C)



PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Voltage Gain	Gv	V _{IN} =10mV, f=1KHz		-3		dB
Reduced Voltage Characteristic	ΔGvV	V _{IN} =10mV, f=1KHz, V _{CC} =4.5V→1.5V		-1.2	-3.5	dB
Frequency Characteristic	ΔGvF	f=1KHz to 110Hz			-1	dB
Input Resistance	Z _{in}	f=1KHz	25			MΩ
Output Resistance	Z _o	f=1KHz			700	Ω
Total Harmonic distortion	THD	V _{IN} =30mV, f=1KHz		1		%
Output Noise Voltage	V _{NO}	V _{IN} =0, A CURVE			-110	dB